

Symbol	Parameter		Ratings	Units	
V <sub>DSS</sub>	Drain-to-Source Voltage		40	V	
V <sub>GS</sub>	Gate-to-Source Voltage		±20	V	
I <sub>D</sub>	Drain Current - Continuous (V <sub>GS</sub> =10) (Note 1)	T <sub>C</sub> =25°C	300	Α	
	Pulsed Drain Current	T <sub>C</sub> = 25°C	See Figure 4		
E <sub>AS</sub>	Single Pulse Avalanche Energy	(Note 2)	1064	mJ	
	Power Dissipation		429	W	
P <sub>D</sub>	Derate Above 25°C		2.86	W/ºC	
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Temperature		-55 to + 175	°C	
R <sub>0JC</sub>	Thermal Resistance, Junction to Case		0.35	°C/W	
$R_{\theta JA}$	Maximum Thermal Resistance, Junction to Ambient	(Note 3)	43	°C/W	

Notes:

1: Current is limited by bondwire configuration.

2: Starting  $T_J = 25^{\circ}$ C, L = 0.3mH,  $I_{AS} = 84A$ ,  $V_{DD} = 40V$  during inductor charging and  $V_{DD} = 0V$  during time in avalanche.

3: R<sub>0JA</sub> is the sum of the junction-to-case and case-to-ambient thermal resistance, where the case thermal reference is defined as the solder mounting surface of the drain pins. R<sub>0JC</sub> is guaranteed by design, while R<sub>0JA</sub> is determined by the board design. The maximum rating presented here is based on mounting on a 1 in<sup>2</sup> pad of 2oz copper.

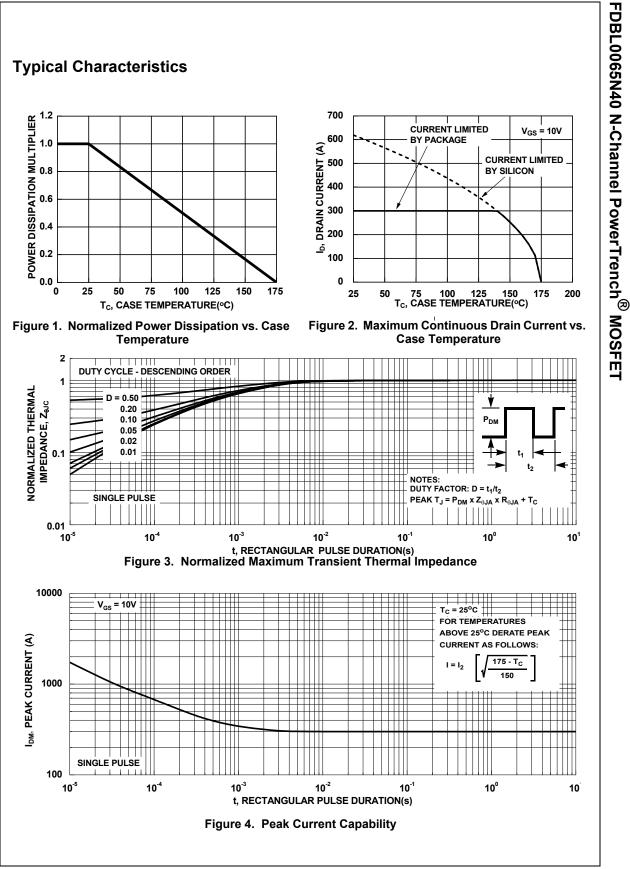
# Package Marking and Ordering Information

Device Marking	Device	Package			
FDBL0065N40	FDBL0065N40	MO-299A	-	-	-

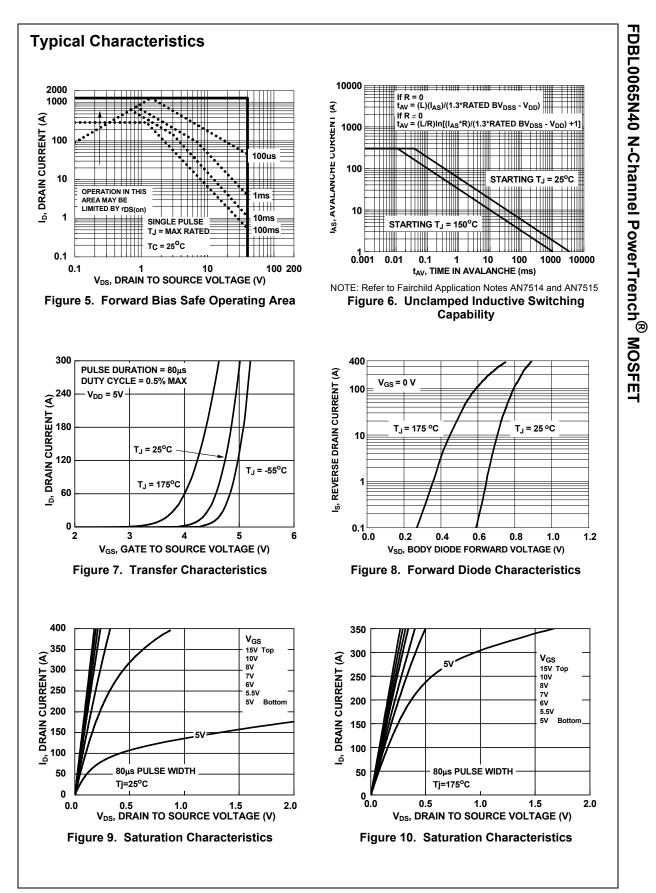
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Symbol	Parameter	Test C	onditions	Min.	Тур.	Max.	Units
	racteristics				,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,	-	
B <sub>VDSS</sub>	Drain-to-Source Breakdown Voltage	I <sub>D</sub> = 250μA, V <sub>GS</sub> = 0V		40	-	-	V
		V <sub>DS</sub> =40V, T		-	-	1	μA
IDSS	Drain-to-Source Leakage Current	V <sub>GS</sub> = 0V T	<sub>J</sub> = 175 <sup>o</sup> C (Note 4)	-	-	1	mA
I <sub>GSS</sub>	Gate-to-Source Leakage Current	$V_{GS} = \pm 20V$		-	-	±100	nA
On Cha	racteristics						
V <sub>GS(th)</sub>	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}, I_D =$	= 250μA	2.0	3.0	4.0	V
D	Drain to Source On Resistance	D /	J = 25°C	-	0.50	0.65	mΩ
R <sub>DS(on)</sub>		V <sub>GS</sub> = 10V T	<sub>J</sub> = 175 <sup>o</sup> C (Note 4)	-	0.86	1.10	mΩ
Dynami C <sub>iss</sub>	c Characteristics				15900	-	рF
C <sub>oss</sub>	Output Capacitance	V <sub>DS</sub> = 25V, V <sub>GS</sub> = 0V, f = 1MHz		-	4025	-	p. pF
C <sub>rss</sub>	Reverse Transfer Capacitance			-	604	-	pF
R <sub>a</sub>	Gate Resistance			-	2.6	-	Ω
Q <sub>g(ToT)</sub>	Total Gate Charge at 10V	V <sub>GS</sub> = 0 to 10V	V <sub>DD</sub> = 20V	-	220	296	nC
$Q_{g(th)}$	Threshold Gate Charge	$V_{GS} = 0$ to 2V	$I_{\rm D} = 80A$	-	29	39	nC
Q <sub>gs</sub>	Gate to Source Gate Charge			-	73	-	nC
Q <sub>gd</sub>	Gate to Drain "Miller" Charge			-	41	-	nC
Switchi	ng Characteristics				-	221	ns
t <sub>d(on)</sub>	Turn-On Delay			-	54	-	ns
r	Rise Time	V <sub>DD</sub> = 20V, I <sub>D</sub> =	= 80A,	-	82	-	ns
t <sub>d(off)</sub>	Turn-Off Delay	V <sub>GS</sub> = 10V, R <sub>G</sub>		-	106	-	ns
t <sub>f</sub>	Fall Time			-	52	-	ns
t <sub>off</sub>	Turn-Off Time			-	-	215	ns
Drain-S	ource Diode Characteristics						
V <sub>SD</sub>	Source to Drain Diode Voltage	I <sub>SD</sub> =80A, V <sub>GS</sub> = 0V		-	-	1.25	V
- 20	-	I <sub>SD</sub> = 40A, V <sub>GS</sub>		-	-	1.2	V
t <sub>rr</sub>	Reverse Recovery Time	$I_{F} = 80A, dI_{SD}/dt = 100A/\mu s,$		-	119	133	ns
Q <sub>rr</sub>	Reverse Recovery Charge		V <sub>DD</sub> =32V		228	274	nC

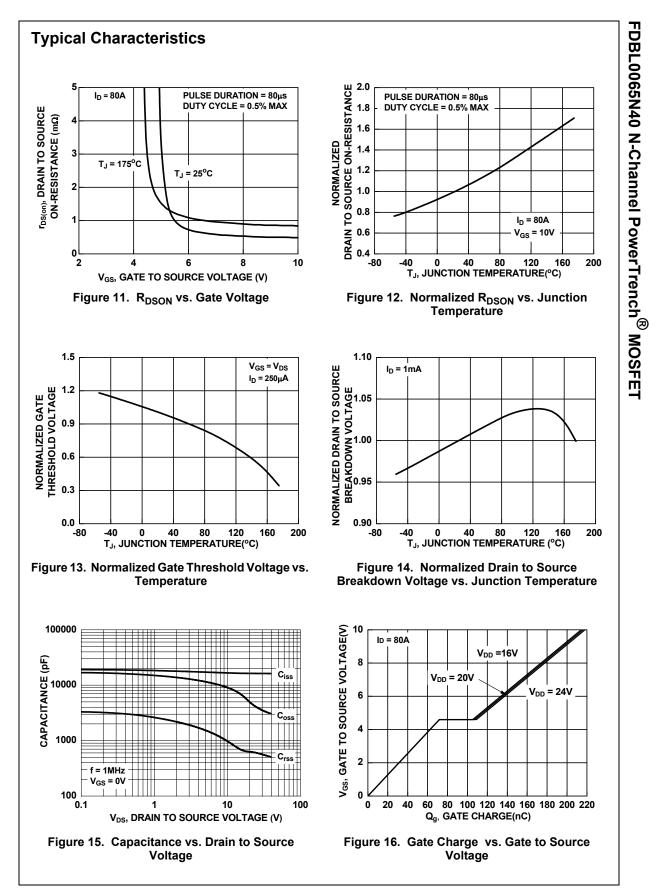
4: The maximum value is specified by design at  $T_J$  = 175°C. Product is not tested to this condition in production.



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FDBL0065N40 Rev.C3



FDBL0065N40 Rev.C3



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